

# Topological Phases in the Single-Layer FeSe

Ningning Hao<sup>1,2</sup> and Jiangping Hu<sup>1,2,3</sup>

<sup>1</sup>*Beijing National Laboratory for Condensed Matter Physics and Institute of Physics,  
Chinese Academy of Sciences, P. O. Box 603, Beijing 100190, China*

<sup>2</sup>*Department of Physics, Purdue University, West Lafayette, Indiana 47907, USA*

<sup>3</sup>*Collaborative Innovation Center of Quantum Matter, Beijing, China*

A distinct electronic structure was observed in the single-layer FeSe which shows surprising high temperature superconductivity over 65K. Here we demonstrate that the electronic structure can be explained by the strain effect due to substrates. More importantly, we find that this electronic structure can be tuned into robust topological phases from a topologically trivial metallic phase by the spin-orbital interaction and couplings to substrates. The topological phase is robust against any perturbations that preserve the time-reversal symmetry. Our studies suggest that topological phases and topologically related properties such as Majorana Fermions can be realized in iron-based high  $T_c$  superconductors.

The single-layer (SL) FeSe film[1–7] that is epitaxially grown on SrTiO<sub>3</sub>(001) surface exhibits several remarkable unique features compared with the bulk FeSe[8, 9] and other Fe-based superconductors[10, 11]. In the bulk FeSe, the superconducting transition temperature,  $T_c \sim 8\text{K}$ [8], and the electronic structure is characterized by the presence of both hole pockets around  $\Gamma$  point and electron pockets around M point in the first Brillouin zone[BZ][12, 13]. In the SL FeSe,  $T_c$  exceeding 65K was observed[1]. Furthermore, there are only electron pockets around M point and the hole pockets at  $\Gamma$  point are absent[2–4]. The ARPES experiments[2, 3] have shown that the electronic structure of the SL FeSe cannot be obtained through the directly rigid band shifting because a new band gap below Fermi surface is developed at M point. The origin of the novel electronic structure and its relation to the high  $T_c$  in the SL FeSe remain as open issues.

Here we first discuss the origin of the novel band structure as a result of the lattice mismatch between the FeSe and substrate SrTiO<sub>3</sub>. We demonstrate that the lattice distortion can induce a phase transition around M point from a gapless phase to a gaped phase and simultaneously suppress the hole-like band at  $\Gamma$  point.

It is known that the electronic structure in the bulk FeSe is rather two-dimensional and is determined by the single FeSe tri-layer structure as shown in Fig. 1(a) and (b) in which the unit cell includes two Fe labeled as A and B and two Se. The band structure calculations from the density functional theory show that only the five 3d orbitals of Fe play the significant roles near Fermi surfaces[12]. A general effective d-orbitals model for the band structure in the real space can be written as

$$H_t = \sum_{\alpha, \beta, \sigma} \sum_{mn} \sum_{ij} (t_{\alpha\beta, ij}^{mn} + \epsilon_m \delta_{mn} \delta_{\alpha\beta} \delta_{ij}) d_{\alpha, m, \sigma}^\dagger(i) d_{\beta, n, \sigma}(j) \quad (1)$$

Here,  $\alpha, \beta$  label two different Fe A and B.  $\sigma$  labels spin.  $m, n$  label five d orbitals:  $(d_{xz}, d_{yz}, d_{x^2-y^2}, d_{xy}, d_{z^2})$ .  $i, j$  label lattice sites.  $t_{\alpha\beta, ij}^{mn}$  is the corresponding hopping parameters.  $\epsilon_m$  is the on-site energy of d orbital.  $d_{\alpha, m, \sigma}^\dagger(i)$  creates an spin- $\sigma$  electron in  $m$ th orbital of  $\alpha$  Fe at site  $i$ . In the momentum space, the Hamiltonian can be written as

$$H_t = \sum_k \phi^\dagger(k) A(k) \phi(k) + \sum_{k'} \phi^\dagger(k') A(k') \phi(k') \quad (2)$$

Here,  $k$  is defined in the BZ of one Fe unit cell, and  $k' = k + Q$  with  $Q = (\pi, \pi)$ .  $\phi(k) = [d_{xz}(k), d_{yz}(k), d_{x^2-y^2}(k), d_{xy}(k), d_{z^2}(k)]^T$ .  $A(k)$  has been widely utilized to describe the electronic structure of all kinds of iron-based superconductors[14, 15]. The difference between the one Fe unit cell and two Fe unit cell pictures can be found in section I of supplementary materials.

The Fermi surface and band structure along high-symmetry lines are shown in Fig. 1(c) and (d). In Fig. 1(c), there are three hole pockets around the  $\Gamma$  point and the two electron pockets around M point. We have specified that the black pockets in Fig.1(c) are from  $A(k)$  while the red pockets from  $A(k')$ . In Fig. 1(d), the solid or dashed lines denote the bands from  $A(k)$  or  $A(k')$ .

In Fig. 1, there is no gap opening in the band structure at M point. To gain the insight of the gap opening observed experimentally in the SL FeSe, we analyze the symmetry characters of the bands. As shown in Fig. 1, there are four bands along  $\Gamma$ -M direction near Fermi surfaces. Each  $A(k)$  and  $A(k')$  contribute two bands. The

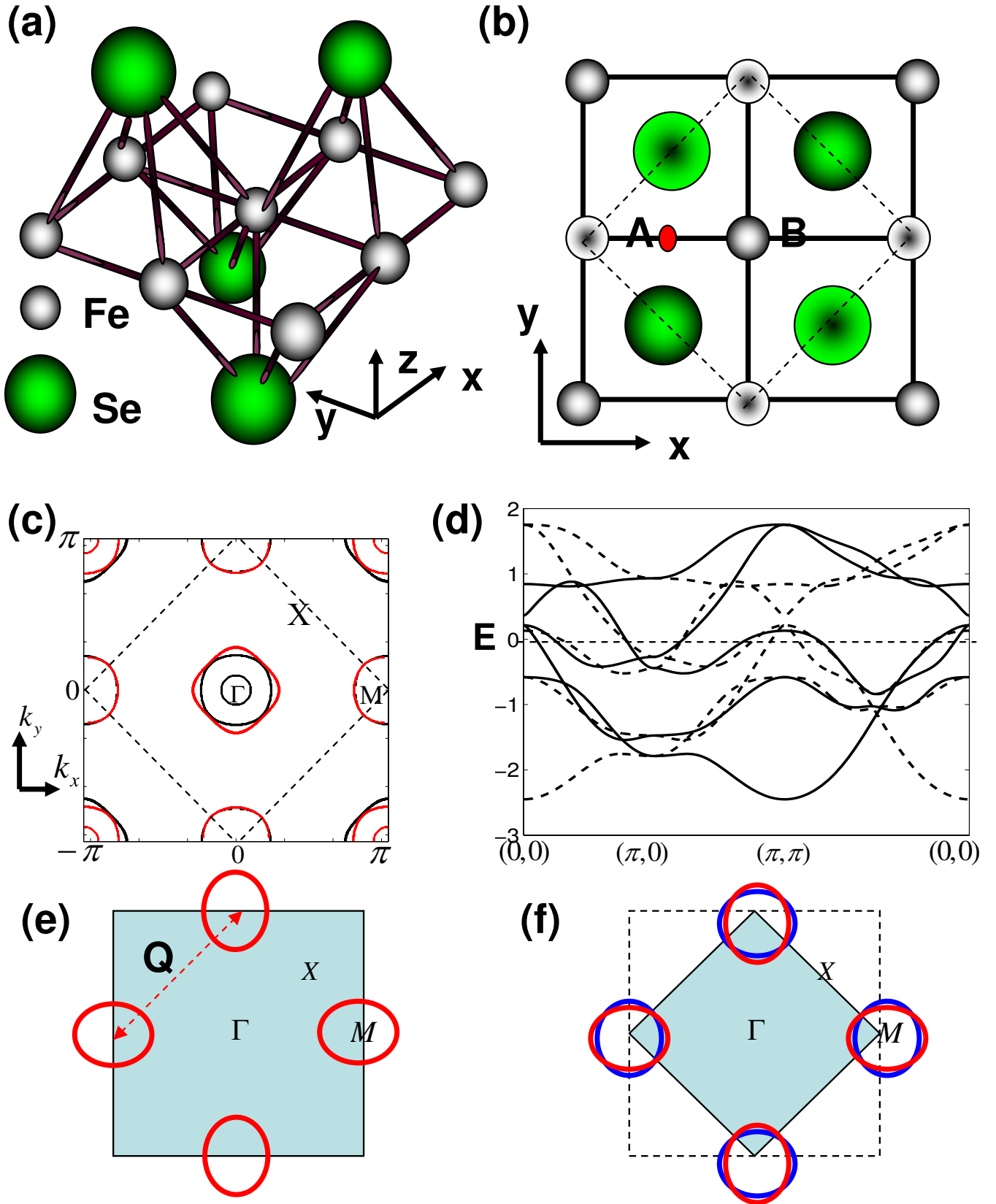


FIG. 1: (Color Online) (a) The lattice structure of FeSe. (b) The planform of (a), the two-Fe unit cell is enclosed by the dashed lines with the two Fe sublattice labeled with A and B. The inverse center is labeled by the red elliptic spot at the mid point of A-B link. (c) the fermi surface for the bulk FeSe, with three hole pockets locate around  $\Gamma$  point and two electron pockets around  $M$  point in the two-Fe BZ. The two-Fe BZ is enclosed by the dashed lines. (d) The band structure along high-symmetry lines. (e) and (f) The schematic fermi surface for SL FeSe are shown in one Fe and two Fe unit cell picture. The shadow region is the corresponding BZ. In (e),  $Q=(\pi, \pi)$  is the folding wave-vector.

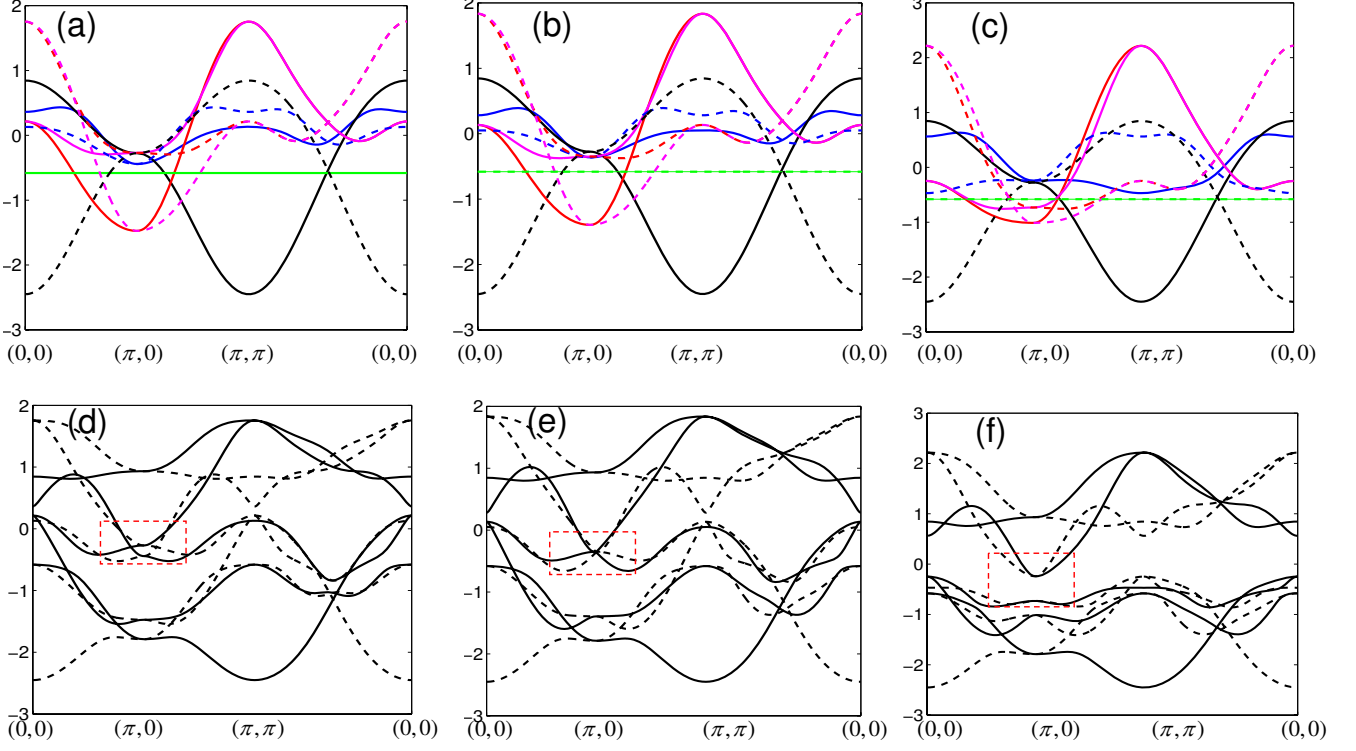


FIG. 2: (Color Online) (a)-(c) The bands structures along high-symmetry line for the case without interorbital hoppings. (a) for the bulk case. (b) the adjusted parameters are  $t_{xy}^{44} = 0.066$ ,  $t_x^{14} = 0.405$ ,  $t_x^{11} = -0.120$ . (c)  $t_{xy}^{44} = 0.036$ ,  $t_x^{44} = 0.163$ ,  $t_x^{14} = 0.405$ ,  $t_x^{11} = -0.311$ . The solid/dashed lines are from  $A(k)/A(k+Q)$ . The red/magenta/blue/black/green lines are the  $d_{xz}/d_{yz}/d_{xy}/d_{x^2-y^2}/d_{z^2}$  bands. (d)-(f) are the cases with inter-orbital hoppings and correspond to (a)-(c).

bands contributed from  $A(k)$  and  $A(k')$  have opposite parity[16, 17]. The two bands from  $A(k)$  belong to  $A_2$  and  $B_2$  representations[18], which is the reason why the two bands can cross each other without showing the sign of hybridization. However, the two bands from  $A(k')$  belong to the same  $B_1$  representations[18]. If these two bands across each other, the hybridization must take place. We notice that these two bands are attributed to the  $d_{xz}$  and  $d_{xy}$  orbitals respectively near M point. Moreover, the symmetry characters of the bands do not depend on the inter-orbital couplings because the couplings between two different d-orbitals at high symmetry points, such as  $\Gamma$  and  $M$ , vanish. Therefore, we can adjust the relative energy difference between  $d_{xz}$  and  $d_{xy}$  at M points to create an crossing between the two bands. such an crossing can result in a gap opening at M point because of the hybridization.

To confirm above symmetric analysis, we present an evolution of the band structure by manipulating hopping parameters in Fig.2. The bulk band structures are shown in Fig.2 (a) and (d). Note that we set all inter-orbital hoppings zero in Fig.2 (a) in order to clearly distinguish the five  $d$ -orbital bands. In Fig. 2 (a), the red-dashed  $d_{xz}$  band and the blue-dashed  $d_{xy}$  band has no cross along  $(0,0)$ - $(\pi,0)$  line. In Fig. 2 (d), there is no band gap opening around M point, i.e.,  $(\pi,0)$  (see the red rectangle region in Fig. 2(d)). When we adjust the values of some hopping parameters (See the caption of Fig. 2), the red-dashed  $d_{xz}$  band is pushed down and the blue-dashed  $d_{xy}$  band is pushed up. The critical case is shown in Fig. 2 (b), the two bands meet each other at M point. Then, the continued push leads to the cross between red-dashed  $d_{xz}$  and blue-dashed  $d_{xy}$  bands at some point between  $(0,0)$  and  $(\pi,0)$  (See Fig. 2 (c)). Turning on the inter-orbital hoppings, we obtain a new band structure shown in Fig. 2 (f). Compared with the bulk bands in Fig. 2(d), the bands in Fig. 2(f) present some new feature, such as (1) the hole pockets around  $\Gamma$  point are pushed down the fermi energy with only electron pockets around M point surviving. (2) the band top of hole pockets nearly has same energy as the band bottom of electron pockets. (3) there is a band gap opened at M point (See the red rectangle region Fig. 2 (f)). These features of band structure shown in Fig. 2 (f) are comparable to the ARPES observations[2, 3].

From Fig. 2, we can find that the evolution of band structure from bulk FeSe to a SL FeSe is strongly sensitive

to the change of a single hopping parameter  $t_x^{11}$ , i.e., the amplitude of intra- $d_{xz}/d_{yz}$  hopping along  $x/y$  directions. Namely, the nearest-neighbor intra-orbital hoppings for  $d_{xz}$  and  $d_{yz}$  changes from the strong anisotropy in the bulk FeSe to near isotropy in the SL FeSe. (See the Fig.7 in supplementary materials). We argue that this is the essential reason to drive the electronic structure of the SL FeSe. The SL FeSe film is epitaxially grown on SrTiO<sub>3</sub>(001) surface. Consequently, the lattice constant for the SL FeSe film should match the lattice constant for SrTiO<sub>3</sub>, i.e., 3.905Å. Compared with the bulk FeSe with lattice constant 3.76Å[8], the apparent lattice mismatch between FeSe and SrTiO<sub>3</sub> should exert a strong tensile strain on the FeSe film, and drive the lattice distortion for the FeSe film[4, 5]. The lattice distortion naturally induces the changes of hopping. The influence of lattice distortion to the hopping parameters is discussed in details in the section II of supplementary materials.

After obtaining the new band structure, we can ask whether the new band gap at  $M$  point (See the red rectangle region Fig. 2 (f)) is topologically trivial or nontrivial when the spin-orbital coupling (SOC) is considered? As the  $t_{2g}$  orbitals are significant near Fermi surface, we can write SOC within the  $t_{2g}$  subset. Up to the next nearest neighbor, the general SOC Hamiltonian in momentum space can be written as

$$H_{so} = H_{so1} + H_{so2}, \quad (3)$$

$$H_{so1} = \sum_{\tilde{k}=k,k'} (-1)^\sigma \lambda_\perp(\tilde{k}) d_{xz,\sigma}^\dagger(\tilde{k}) d_{yz,\sigma}(\tilde{k}) + H.c., \quad (4)$$

$$H_{so2} = \sum_{\tilde{k}=k,k'} [i\lambda_{||,xz}(\tilde{k}) d_{xz,\uparrow}^\dagger(\tilde{k}) + \lambda_{||,yz}(\tilde{k}) d_{yz,\uparrow}^\dagger(\tilde{k})] d_{xy,\downarrow}(\tilde{k} + Q) + H.c. \\ - \sum_{\tilde{k}=k,k'} d_{xy,\uparrow}^\dagger(\tilde{k}) [i\lambda_{||,xz}(\tilde{k}) d_{xz,\downarrow}(\tilde{k} + Q) + \lambda_{||,yz}(\tilde{k}) d_{yz,\downarrow}(\tilde{k} + Q)] + H.c. \quad (5)$$

Here,  $\sigma = \mp$  for spin  $\uparrow$  or  $\downarrow$ .  $\lambda_\perp(\tilde{k}) = (\lambda_\perp^o + 4\lambda_\perp^{nn} \cos \tilde{k}_x \cos \tilde{k}_y)$ .  $\lambda_{||,xz/yz}(\tilde{k}) = \lambda_{||}^o + 2\lambda_{||}^n \cos \tilde{k}_{x/y}$ . The index  $\alpha = o, n, nn$  in the  $\lambda_{||,\perp}^\alpha$  indicate the onsite, nearest neighbor, and next nearest neighbor SOC respectively.  $H_{so1}$  describes the SOC between  $d_{xz}$  and  $d_{yz}$  orbitals. This term does not flip spin and also conserves momentum with respect to the 1-Fe unit cell.  $H_{so2}$  describes the SOC between  $d_{xy}$  and  $d_{xz,yz}$ . This term flips spin and does not conserve momentum with respect to the 1-Fe unit cell. Therefore,  $H_{so2}$  essentially break the non-symmorphic lattice symmetry in the SL FeSe, namely, an one-unit translation along the Fe-Fe direction followed by a mirror reflection with respect to the layer[19]. In the presence of  $H_{so2}$ , the 2-Fe unit cell can not be reduction to the 1-Fe unit cell.

The  $H_{so2}$  is not the only term that breaks the reduction to the 1-Fe unit cell. If we consider the effect of a substrate, the space inversion symmetry is naturally broken for the SL FeSe. Such a parity breaking can also result in a term that only preserves the 2-Fe unit cell[16],

$$H_s = \sum_{m,\sigma} \sum_{\tilde{k}=k,k'} \xi_s(\tilde{k}) d_{m,\sigma}^\dagger(\tilde{k}) d_{m,\sigma}(\tilde{k} + Q). \quad (6)$$

Here,  $\xi_s(\tilde{k})$  measures this parity breaking effect. Likewise, we only focus on three  $t_{2g}$  orbitals. If we take a constant  $\xi_s(\tilde{k})$ , the term describes a staggered potential in the iron square lattice.

The full Hamiltonian for the electronic structure of the SL FeSe with a substrate is a combination of  $H_t$ ,  $H_{so}$  and  $H_s$ , namely,

$$H = H_t + H_{so1} + H_{so2} + H_s. \quad (7)$$

The last two terms in  $H$  only preserve the translational symmetry with respect to the 2-Fe unit cell.

We first concentrate on the effect of  $H_{so1}$  which preserves the 1-Fe unit cell. Namely, we ignore both  $H_{so2}$  and  $H_s$ . The glancing features can be spied through the numerical results of the band structure of the Hamiltonian  $H = H_t + H_{so1}$ . The results are shown in Fig. 3. In Fig. 3 (a)-(c), it is explicitly shown that the band gap undergoes a closing and reopening process at  $M$  point when  $\lambda_\perp^o$  and  $\lambda_\perp^{nn}$  are tuned from zero to some finite values. Such a phenomena is a strong indication of a topological phase transition[20, 21]. Fig. 3 (d)-(i) provide a clear proof of the occurrence of the topological phase transition. The spectra in Fig. 3(d)-(f) and Fig.3 (g)-(i) are plotted within the 1-Fe unit cell and the 2-Fe unit cell respectively. The latter can be obtained through folding the 1-Fe unit cell picture with the folding wave vector  $Q = (\pi, \pi)$ . It is clear that the signature of the topological phase, gapless edge states, emerges after the band gap reopens.

We can also construct an effective Hamiltonian to describe the topological transition. The detailed derivation is presented in the section III of supplementary materials. Here, we only briefly summarize the result. We define the

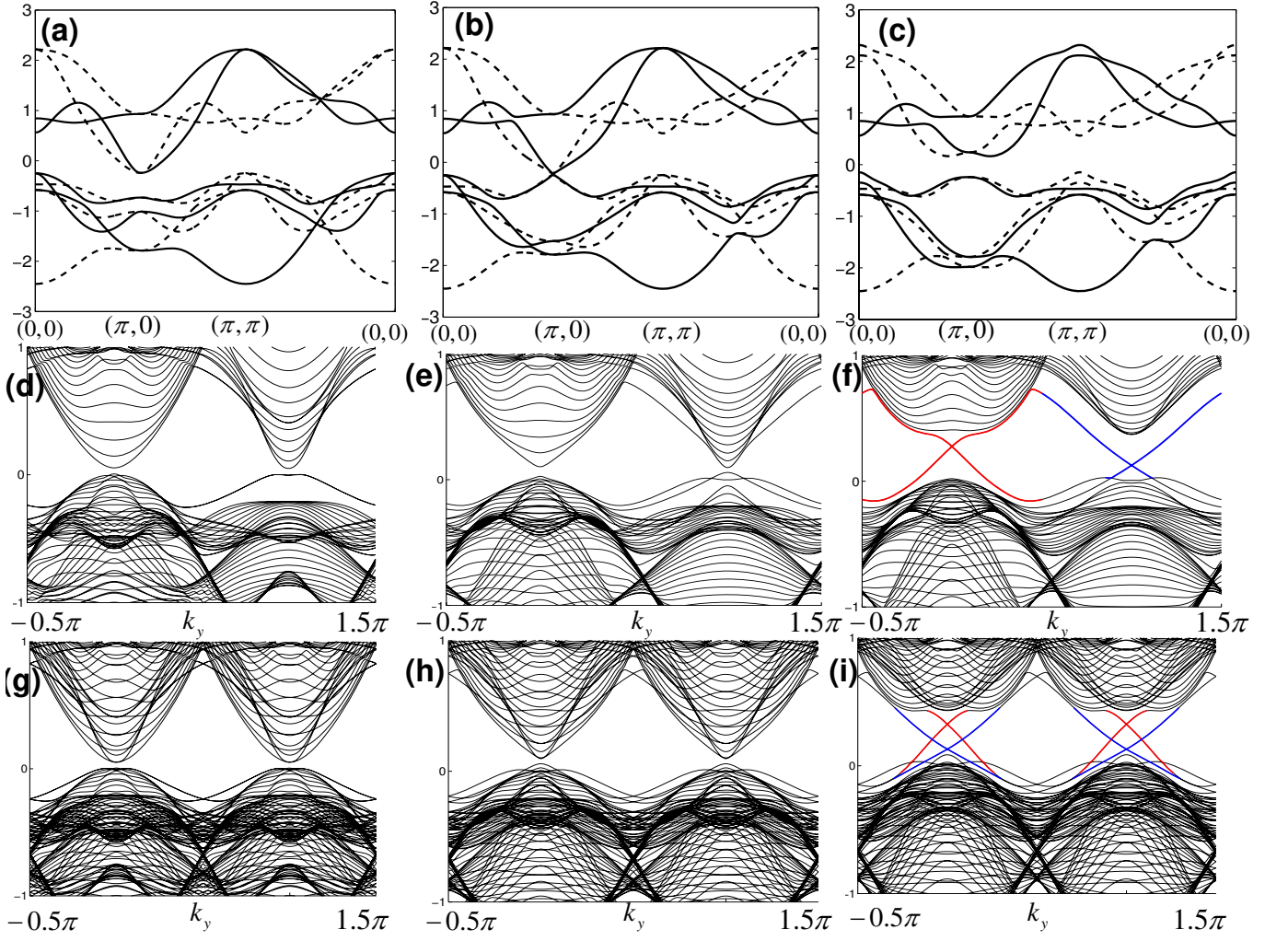


FIG. 3: (Color online) (a) (b) (c) The spectrum along high-symmetry line for different spin-orbital coupling parameters with (a)  $\lambda_{\perp}^o = 0$ ,  $\lambda_{\perp}^{nn} = 0$  (b)  $\lambda_{\perp}^o = 0.32$ ,  $\lambda_{\perp}^{nn} = 0.08$  (c)  $\lambda_{\perp}^o = 0.5$ ,  $\lambda_{\perp}^{nn} = 0.12$ . Other parameters  $\lambda_{\parallel}^o$ ,  $\lambda_{\parallel}^n$  and  $\xi_s$  are set zero. (d) (e) (f) (g) (h) (i) are the corresponding one Fe unit cell (two Fe unit cell) edge spectrum with open boundary along  $x$  direction. the width of the single-layer film is 21 in unit of lattice constant.

new basis for  $d_{xz}$  and  $d_{yz}$  orbitals according to the eigenstates of azimuthal quantum number  $l = 2$  and magnetic quantum number  $m = \pm 1$  i.e.  $d_{(2,1),\sigma}(\tilde{k}) = -\frac{1}{\sqrt{2}}[d_{xz,\sigma}(\tilde{k}) + id_{yz,\sigma}(\tilde{k})]$ ,  $d_{(2,-1),\sigma}(\tilde{k}) = \frac{1}{\sqrt{2}}[d_{xz,\sigma}(\tilde{k}) - id_{yz,\sigma}(\tilde{k})]$ . Around each  $M$  point, the band structure can be spanned by  $\Psi_{eff}(\tilde{k}) = [\phi_{eff,\uparrow}(\tilde{k}), \phi_{eff,\downarrow}(\tilde{k})]^T$  with  $\phi_{eff,\sigma}(\tilde{k}) = [d_{xy,\sigma}(\tilde{k}), d_{(2,-1),\sigma}(\tilde{k})]^T$  and is described by the effective Hamiltonian,

$$H_{eff} = \sum_{\tilde{k}=k,k'} \Psi_{eff}^{\dagger}(\tilde{k}) A_{eff}(\tilde{k}) \Psi_{eff}(\tilde{k}) \quad (8)$$

where,

$$A_{eff}(\tilde{k}) = \sum_{a=0}^5 \varepsilon_a(\tilde{k}) \Gamma^a + \sum_{a<b=1}^5 \varepsilon_{ab}(\tilde{k}) \Gamma^{ab} \quad (9)$$

is a  $4 \times 4$  matrix. The  $\Gamma$  matrices are defined as  $\Gamma^{(0,1,2,3,4,5)} = (\tau^0 \otimes s^0, \tau^0 \otimes s^z, \tau^0 \otimes s^y, \tau^z \otimes s^x, \tau^y \otimes s^x, \tau^x \otimes s^x)$ , where the Pauli matrices  $\tau$  and  $s$  span the orbital and spin subspaces.  $\Gamma^{ab} = [\Gamma^a, \Gamma^b]/(2i)$ . The non-zero elements are  $\varepsilon_{0/1}(\tilde{k}) = \frac{1}{2}[E_{xy}(\tilde{k}) \pm E_{(2,-1)}(\tilde{k}) \pm |\lambda_{\perp}(\tilde{k})|]$  and  $\varepsilon_{12/13}(\tilde{k}) = \pm \sqrt{2} t_x^{14} \sin \tilde{k}_{y/x}$ , in which  $E_{xy}(\tilde{k}) = A_{44}(\tilde{k})$  and  $E_{(2,-1)}(\tilde{k}) = \frac{1}{2}[A_{11}(\tilde{k}) + A_{22}(\tilde{k})]$ .

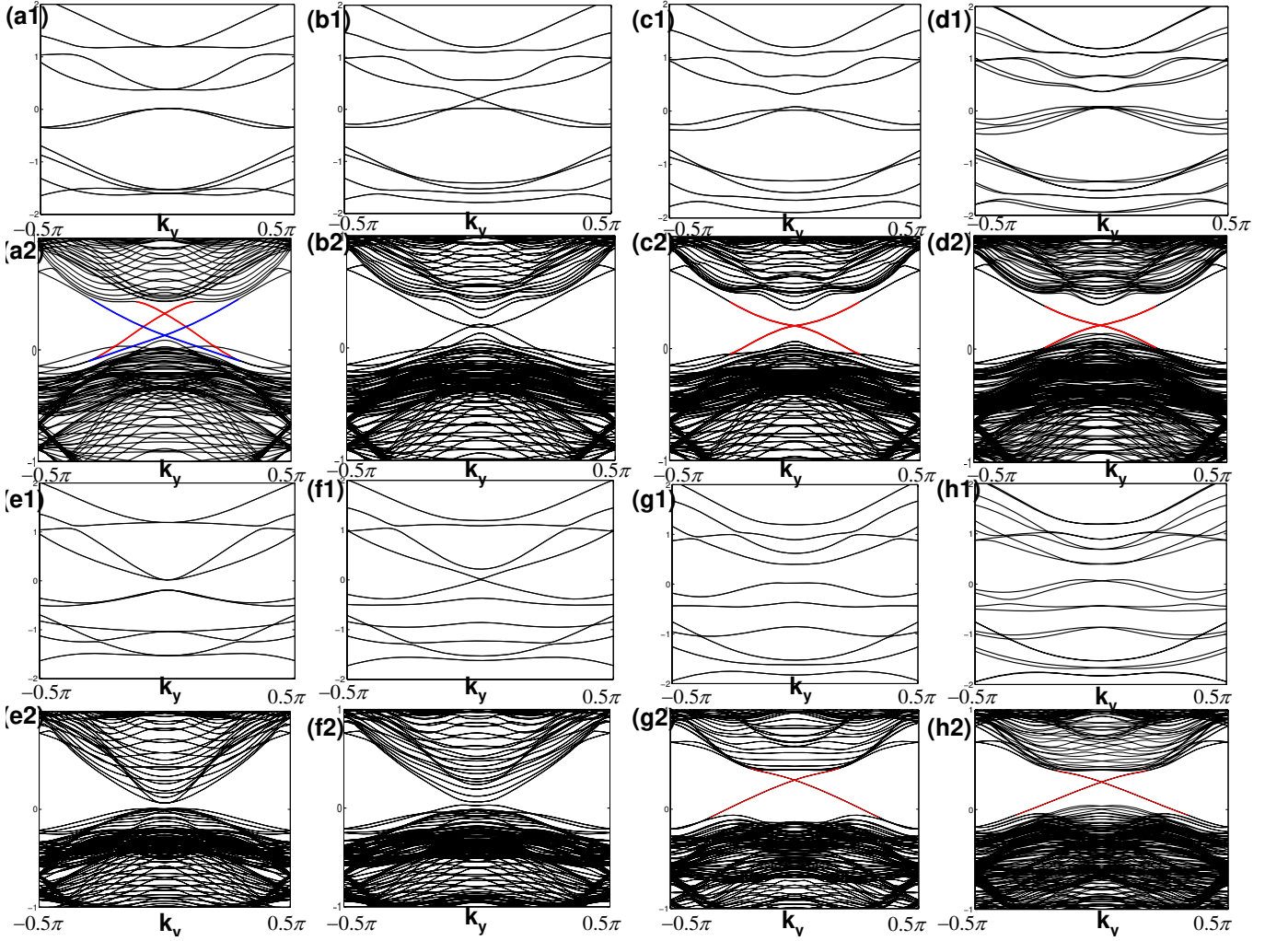


FIG. 4: (Color online) (a1)-(d1) The evolution of spectrum with  $k_x = \pi$ ,  $k_y \in [-\frac{\pi}{2}, \frac{\pi}{2}]$  for parameters  $(\lambda_{\perp}^o, \lambda_{\perp}^{nn}, \lambda_{\parallel}^o, \lambda_{\parallel}^n, \xi_s)$  with the values (0.5, -0.12, 0, 0, 0) in (a1), (0.5, -0.12, 0, 0, 0.19) in (b1), (0.5, -0.12, 0, 0, 0.3) in (c1) and (0.5, -0.12, 0.2, 0.3) in (d1). (a2)-(d2) are the corresponding edge spectrum with open boundary along x direction. (a2) is weak topological phase (c2) and (d2) are strong topological phase. (b2) is the critical point. (e1)-(h1) The evolution of spectrum with  $k_x = \pi$ ,  $k_y \in [-\frac{\pi}{2}, \frac{\pi}{2}]$  for parameters  $(\lambda_{\perp}^o, \lambda_{\perp}^{nn}, \lambda_{\parallel}^o, \lambda_{\parallel}^n, \xi_s)$  with the values (0.2, -0.05, 0, 0, 0) in (e1), (0.2, -0.05, 0, 0, 0.2) in (f1), (0.2, -0.05, 0, 0, 0.6) in (g1) and (0.2, -0.05, 0.2, 0.6) in (h1). (e2)-(h2) are the corresponding edge spectrum with open boundary along x direction. (e2) is trivial phase (g2) and (h2) are strong topological phase. (f2) is the critical point. In (a2)-(d2) and (e2)-(h2), the width of the single-layer film is 21 unit of Fe-Fe lattice constant.

The above effective Hamiltonian has the same form as those for HgTe quantum wells[21]. At each  $M$  point, the band gap of Eq. (9) is measured by a Dirac mass  $\varepsilon_1(\tilde{k})$ . When the  $\lambda_{\perp}(\tilde{k})$  overcomes the trivial band gap measured by  $E_{xy}(\tilde{k}) - E_{(2,-1)}(\tilde{k})$ , namely, the mass  $\varepsilon_1(\tilde{k}) < 0$  changes its sign from positive to negative, a trivial to nontrivial topological phase transition takes place.

We notice that there are even number (two) nontrivial Dirac cone structures in the Hamiltonian  $H = H_t + H_{so1}$  as shown in Fig. 3. This is because that the Hamiltonian preserves the full non-symmorphic lattice symmetry so that the band structure decouples into two independent parts in the view of the 2-Fe unit cell. In the 2-Fe unit cell BZ, there is a nontrivial Dirac cone structure at the BZ zone corner for each part. If we understand this in the 1-Fe unit cell picture, a nontrivial Dirac cone structure exists at each  $M$  point of the 1-Fe BZ. As each Dirac cone structure results in a pair of edge states in a  $Z_2$  time reversal invariant topological phase[20, 21], there are two pairs of edge states in this topological phases as shown in Fig. 3. With even pairs of edge states, the topological phase essentially is unstable. One can imagine that if any perturbations that break non-symmorphic lattice symmetry may lead to a coupling between two pairs of edge states to open a gap on edge states. Therefore, we call this topological phase as



the weak topological phase[22].

As we mentioned earlier, in the general Hamiltonian (Eq.7) for the SL FeSe with a substrate, both  $H_{so2}$  and  $H_s$  break the non-symmorphic lattice symmetry. Therefore, we have to answer how these two terms affect the weak topological phase. First, we ask the effect of  $H_{so2}$ . Indeed, the spin-flip term in  $H_{so2}$  causes the couplings between the two Dirac cones to create a gap on the edge states. If we assume that the SOC parameter  $\lambda_{||}^o$  is small, the gap opened on the edge states is given by  $\sim |\lambda_{||}^o|^2 / |t_x^{14}|$ . Therefore, in principle, the  $\lambda_{||}^o$  term in Eq. (5) can be considered as a controlling parameter of the gap. The situation is very similar to a topological crystalline insulator[23, 24] and the topological phase in a system with a non-symmorphic lattice symmetry[25].

However, if we turn on  $H_s$ , the situation is drastically different. Rather than destroying the topological phase, we find amazingly that  $H_s$  can stabilize the topological phase and drives the system to a strong topological phase. To understand it, we consider the effective Hamiltonian in Eq.8 describing the weak topological phase. If we add  $H_s$ , for  $\lambda_{\perp}(k) > 0$ , the spectrum becomes  $E(k) = \pm \sqrt{\varepsilon_{12}^2(k) + \varepsilon_{13}^2(k) + [\varepsilon_1(k) \pm \xi_s]^2}$  where we have set effective long-range  $\lambda_{||}^n = 0$  for simplicity. We can find that the effect of  $H_s$  is to change the Dirac masses at the two M points. The changes,  $\varepsilon_1(k) \pm \xi_s$ , are different for the Dirac cones at the two different M points. Therefore,  $H_s$  can create a band inversion only in one Dirac cone but not the other, a case for a strong topological phase with odd number of non-trivial Dirac cones. Thus, the strong topological phase is robust against any non-time-reverse-symmetry broken couplings, including the  $H_{so2}$ , as long as the coupling does not close the bulk energy gap.

The numerical proof of the above analysis is plotted in Fig. 4 in which the edge spectra in Fig. 4(d2) and (h2) clearly indicate a strong topological phase. More specifically, we discuss the strong topological phases in two cases: (1)  $\varepsilon_1(k) < 0$  and (2)  $\varepsilon_1(k) > 0$ . In the first case, when  $|\varepsilon_1(k)| < \xi_s$ , one of non-trivial Dirac cones undergoes another gap-close-and-reopen process, and becomes trivial one with positive mass  $\varepsilon_1(k) + \xi_s > 0$ . At each M point, only one non-trivial Dirac cone survives. The band evolution for this process is shown in Fig. 4(a1)-(d2). In the second case, when  $|\varepsilon_1(k)| < \xi_s$ , one of trivial Dirac cones undergoes a gap-close-and-reopen process, and becomes a non-trivial one with negative mass  $\varepsilon_1(k) - \xi_s < 0$ . At each M point, only one non-trivial Dirac cone emerges. The band evolution for this process is shown in Fig. 4(e1)-(h2). In the first case, one needs relatively large SOC and the parity broken coupling to overcome the trivial band gap and eliminate one non-trivial Dirac cone. In the second case, we can see that a finite value  $H_s$  can create a region of a strong topological phase and can dramatically reduce the critical SOC that is necessary for a topological phase.

The phase diagrams for the topological transition are plotted in Fig. 5. In Fig. 5 (a), we plot the phase diagram for the case of the weak topological phase with respect to the parameters,  $\lambda_{\perp}^o$  and  $\lambda_{\perp}^n$ . Here, the topological metal phase means the hole-like band top at  $\Gamma$  point is higher than the electron-like band bottom around M point so that we cannot tune the system into a full insulating phase, but there is a gap at M point to protect the topological phase. In the topological insulating phase, the edge states propagate along the edges of the materials with opposite speed for different spin components. The pictures of the edge states and the Dirac cones is schematically shown in Fig. 5 (c) and (e) respectively. In Fig 5.(b) we plot the phase diagram for  $\lambda_{\perp}(k) > 0$  case with respect to the parameter  $\xi_s$  in  $H_s$  and  $\lambda_{\perp}(\pi, 0)$ . The A and B points correspond to the cases shown in Fig. 4. (c1) and (g1). The transport picture for the edge states is shown in Fig. 5 (d), which matches the single nontrivial Dirac cone structure shown in Fig. 5(f).

According to the aforementioned discussion, we see that the topological phase is associated to three key parameters: the trivial band gap, the intrinsic spin-orbital coupling strength at M points and the parity broken coupling induced by the substrates. In the FeSe, the bare spin-orbital coupling strength of Fe atoms is around 80mev[26], which can cause a bare energy splitting  $\sim 100$  mev around M point. Considering the renormalization effect (about 4 in FeSe), the real splitting of the band caused by the SOC would be around 25mev. Although we may replace Fe by heavier atoms such as Ru to further increase the SOC strength, the strength of SOC, more or less, is a fixed quantity in the FeSe. However, the trivial band gap and parity-broken coupling at M point can be engineered. With different substrates, the in-plane lattice constant can be tuned from 3.67 to 4Å, which has been recently demonstrated in FeSe/STO/KTO[27] and FeSe/BTO[5] structures. There are a zoo of substrates to play for this interacial engineering[5]. In the supplement, we have shown the qualitative relationship between the gap and lattice parameters. An accurate quantitative prediction of the trivial band gap on different substrates are beyond the capability of any current numerical methods. Nevertheless, as we know that in one limit, the large band gap (about 50mev measured by ARPES[5]) is created in the SL FeSe with STO and BTO substrates, and in the other limit, it vanishes in the bulk FeSe, we can be sure that the interracial engineering technique can create a tunable gap in a SL FeSe. Furthermore, the parity-broken coupling can be larger when the interaction to a substrate is stronger.  $\xi_s$  is tunable with large flexibility. Hence, realizing the topological phase in the SL FeSe is very promising.

It is also possible to further extend above analysis to the bulk materials. According to our above discussions, the difference of the electronic structures between the SL FeSe and the bulk FeSe mainly originates from the lattice

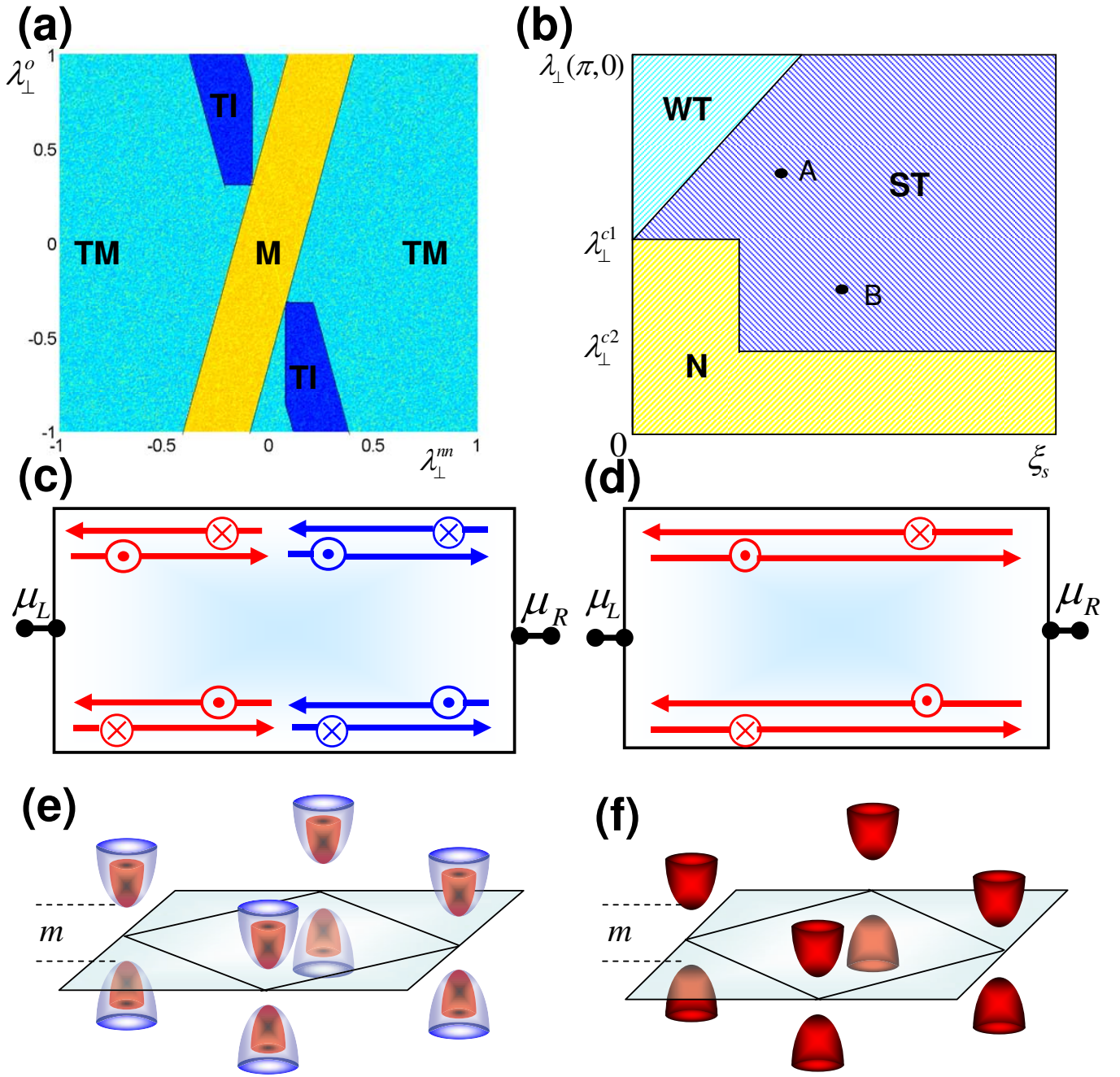


FIG. 5: (Color online) (a) The phase diagram as a function of  $\lambda_\perp^o$  and  $\lambda_\perp^{nn}$ . Here, M, TM and TI label metal, topological metallic and topological insulating phases, respectively. (b) The phase diagram as a function of  $\lambda_\perp(\pi, 0)$  and  $\xi_s$  for  $\lambda_\perp(\pi, 0) > 0$ . Here, WT, ST and N label weak topological, strong topological and normal trivial phases, respectively. (c) and (d) The picture of the accumulation of spin currents in the weak and strong topological insulating phases of SL FeSe with the rectangle geometry. Here, "⊗", "⊙" label majority spin-up and -down. The color corresponds to Fig. 3(i) and Fig. 4(d2) and (h2). (e) The two non-trivial (trivial) Dirac cones with negative (positive) mass  $m$  correspond to Fig. 4 (a1) (Fig.4 (e1)) around  $M$  points in BZ. The red and blue color labels the Dirac cone structures with even and odd parities. (f) The single non-trivial Dirac cone with negative mass  $m$  (Fig. 4 (c1) and (g1)) around  $M$  points in BZ.



distortion induced by the substrate, and the ratio between the height of Se to the Fe plane and the length of Fe-Fe bond uniquely measures this difference. When the ratio declines less than the threshold value, a band gap is opened around  $M$  point. Experimentally, this ratio can be tuned through applying internal or external pressure to the materials. Therefore, we suggest that this topological transition may be realized in the bulk materials of iron-based superconductors if the intensity of SOC is comparable with the band gap around  $M$  point.

We also want to emphasize a great advantage to realize the topological phase in iron-based superconductors. Unlike the conventional hybridized system proposed to realize topological superconductors[28] and Majorana Fermion[29, 30] in which the superconductivity is induced through the proximity effect of conventional s-wave superconductor with the low  $T_c$ , the iron-based materials present high- $T_c$  superconductivity themselves, especially, the SL FeSe shows superconductivity at very high temperature. Hence, a significant importance of this study is to provide a realistic possibility to realize the stable Majorana Fermions at high temperature.

In conclusion, we show that the single layer FeSe present distinct and abundant structures compared with the bulk FeSe through the interaction with the substrates. We predict that there exists strong topological phase in the SL FeSe. It is conceivable that many important physics and applications can emerge when nontrivial topology meets the high- $T_c$  superconductivity.

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